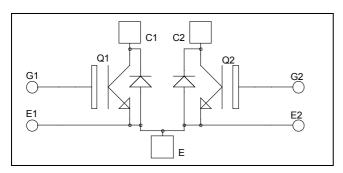


# Dual Common Source NPT IGBT Power Module

 $V_{CES} = 1200V$  $I_{C} = 300A @ Tc = 80°C$ 



#### **Application**

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

#### **Features**

- Non Punch Through (NPT) FAST IGBT
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 50 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T<sub>C</sub> of V<sub>CEsat</sub>
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		1200	V
$I_{C}$	Continuous Collector Current	$T_c = 25^{\circ}C$	400	
	Continuous Conector Current	$T_c = 80^{\circ}C$	300	A
$I_{CM}$	Pulsed Collector Current	$T_c = 25^{\circ}C$	600	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{D}$	Maximum Power Dissipation	$T_c = 25^{\circ}C$	1780	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	600A @ 1200V	

TAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



## All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

## **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
T	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25$ °C			500	4
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{CE} = 1200V$	$T_j = 125$ °C			750	μΑ
V <sub>CE(sat)</sub>	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		3.3	3.9	V
		$I_C = 300A$ $T_j = 12$	$T_j = 125$ °C		4		v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 12mA$		4.5		6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$				±1	μΑ

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			21		
$C_{oes}$	Output Capacitance	$V_{CE} = 25V$			2.9		nF
$C_{res}$	Reverse Transfer Capacitance	f = 1MHz			1.52		ļ
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			120		
$T_{r}$	Rise Time	$V_{GE} = 15V$			50		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 300A$ $R_{G} = 3\Omega$			310		ns
$T_{\mathrm{f}}$	Fall Time				30		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_{C} = 300A$ $R_{G} = 3\Omega$			130		ns
$T_{r}$	Rise Time				60		
$T_{d(off)}$	Turn-off Delay Time				360		
$T_{\rm f}$	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		25		T
$E_{\text{off}}$	Turn-off Switching Energy	$I_C = 300A$ $R_G = 3\Omega$	$T_j = 125^{\circ}C$		15		mJ

Diode ratings and characteristics

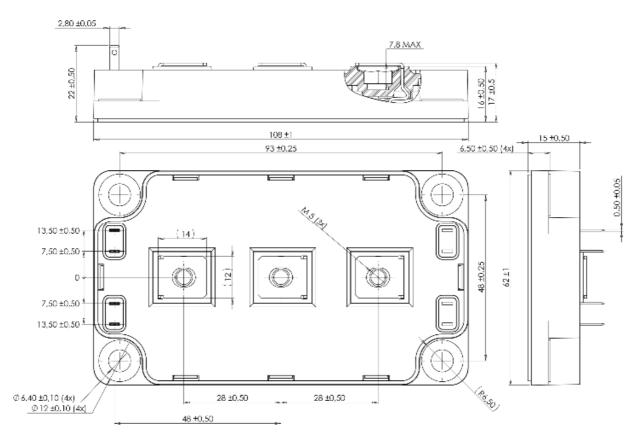
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1200			V
$I_{RM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =1200V	$T_j = 25^{\circ}C$			250	4
1 <sub>RM</sub>			$T_j = 125$ °C			500	μA
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		300		A
$V_{\rm F}$	$I_F$ Diode Forward Voltage $I_F = 300A$	I = 200 A	$T_i = 25^{\circ}C$		2.1		V
V F		$T_{i} = 125^{\circ}C$		1.9		v	
+	Reverse Recovery Time	$I_{F} = 300A \\ V_{R} = 600V \\ di/dt = 4500A/\mu s$	$T_j = 25^{\circ}C$		120		ns
$t_{rr}$			$T_j = 125$ °C		210		
0	Reverse Recovery Charge		$T_j = 25$ °C		22		μС
$Q_{rr}$			$T_{j} = 125^{\circ}C$		43		μС
Er	Reverse Recovery Energy		$T_j = 25$ °C		7		mJ
El			$T_{j} = 125^{\circ}C$		15		1113



## Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance		IGBT			0.07	°C/W
TthJC			Diode			0.12	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range			-40		150	
$T_{STG}$	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	
Wt	Package Weight	•				300	g

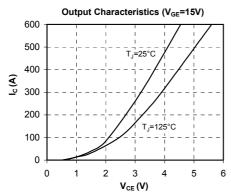
## SP6 Package outline (dimensions in mm)

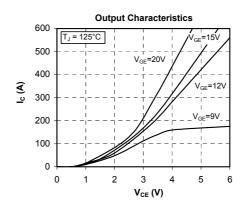


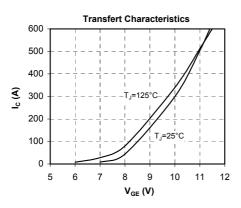
 $See \ application \ note \ APT0601 - Mounting \ Instructions \ for \ SP6 \ Power \ Modules \ on \ www.microsemi.com$ 

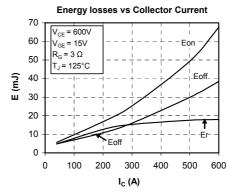


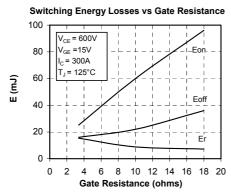
## **Typical Performance Curve**

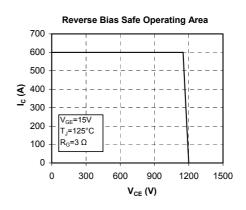


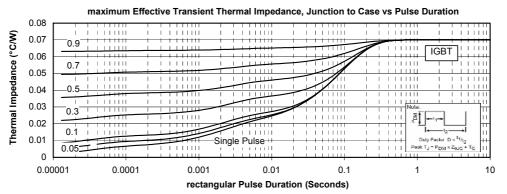




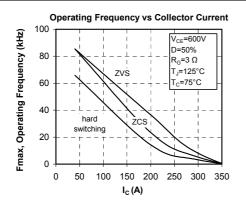


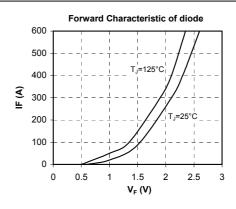


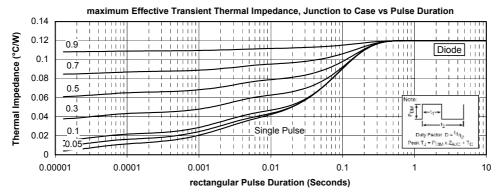














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